Attorney Docket: 040258-0307828 Client Reference: EL01006CDC-D7

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

in re PATENT APPLICATION of: OHMI ET

Confirmation Number: 5332

AL.

FEB 1 5 2005

Application No.: 10/762,520

Group Art Unit: 2818

Filed: January 23, 2004

Examiner: David Vu

Title: FLASH MEMORY DEVICE AND A FABRICATION PROCESS THEREOF,

METHOD OF FORMING A DIELECTRIC FILM

REQUEST FOR COMPLETELY INITIALED PTO-1449 DATED JANUARY 23, 2004

U.S. Patent and Trademark Office Customer Window – Mail Stop Issue Fee Randolph Building 401 Dulany Street Alexandria, VA 22314

Sir:

In reviewing the Notice of Allowance, dated January 27, 2005, Applicants noted that only one page of the three page PTO-1449s that were filed with the application on January 23, 2004 were initialed and returned by the Examiner. The three IDS pages listed all of the prior art filed by the Applicants and cited by the Examiner in the parent application, Serial No. 10/359,701, filed February 7, 2003, which is now allowed.

The present application was allowed on the first Office Action, and copies of all of the other 1449s filed in this application and initialed by the Examiner were enclosed with the Notice of Allowance. However, pages 2 and 3 of the PTO-1449s filed with the application were missing. Applicants enclose copies of the second and third PTO-1449 pages for the Examiner's convenience.

OHMI ET AL. -- 10/762,520 Client/Matter: 040258-0307828

It is respectfully requested that the Examiner initial page 2, containing 2 foreign references, and page 3, containing three non-patent literature references, and return both initialed PTO-1449s by facsimile as soon as possible.

Respectfully submitted,

PILLSBURY WINTHROP LLP

JEFFREY D. KARCESKI

Reg. No. 35914

Tel. No. 703.905.2110 Customer No. 00909

Date: February 15, 2005

P.O. Box 10500 McLean, VA 22102 (703) 905-2000

PTO/SB/08a (08-03)

040258-0307828

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Substitute for form 1449A/PTO		omplete if Known
	Application Number	
INFORMATION DISCLOSURE	Filing Date	01/23/2004
STATEMENT BY APPLICANT	First Named Inventor	TADAHIRO OHMI
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Attorney Docket Number

Examiner	Cito	Decument Number	U. S. PATENT I		Bases Calumna Lines Where
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	FOREIGN PATENT DOCUMENTS						
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered, include copy of this form with next communication to applicant. Applicant's unique citation designation number (optional). 2 See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. 3 Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 4 For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5 Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. O Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

PTO/SB/08b (08-03) Approved for use through 06/30/2006. OMB 0651-0031
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Substitute for form 1449B/PTO		Complete if Known			
				Application Number	
	RMATION DI			Filing Date	01/23/2004
STATEMENT BY APPLICANT				First Named Inventor	TADAHIRO OHMI
(Use as many sheets as necessary)				Art Unit	2818
			9	Examiner Name	
Sheet	1	of	1	Attorney Docket Number	040258-0307828

NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Τ²	
	1	ITO ET AL., "Silicon Oxynitridation WIth Inductively Coupled Oxygen-Nitrogen Mixed Plasma," Jpn. J. Appl. Phys., p. 612-616, (1997).		
	2	HIRAYAMA ET AL., "Low Temperature Growth of High-Integrity Silicon Oxide Films by Oxygen Radical Generated in High-Density Krypton-Plasma," IEEE, p. 249-252, (1999).		
	3	SAITO ET AL., "Low Temperature Formation of Gate-Grade Silicon Nitride Film Employing Microwave-Excitation High-Density Plasma," Technical Report, IEICE, p. 85-90, (1999).		

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Examiner	Date		
Signature	Considered		

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